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APPLICATION NO.	FILING DATE		FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/716,811	11/18/2003		Munesato Kumagai	275412001800	8041
25226	7590	02/10/2006		EXAMINER	
MORRISO 755 PAGE N		ERSTER LLP	ROSASCO, STEPHEN D		
PALO ALTO, CA 94304-1018				ART UNIT	PAPER NUMBER
				1756	

DATE MAILED: 02/10/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

Via No.	App	olication No.	Applicant(s)	- VA
	10/	716,811	KUMAGAI, MUNESATO	
Office Action Sumi	mary Exa	miner	Art Unit	
	Ste	phen Rosasco	1756	
The MAILING DATE of this Period for Reply	communication appears	on the cover sheet wit	h the correspondence address	
A SHORTENED STATUTORY PI WHICHEVER IS LONGER, FROI - Extensions of time may be available under the after SIX (6) MONTHS from the mailing date	M THE MAILING DATE (the provisions of 37 CFR 1.136(a). If of this communication, maximum statutory period will applited for reply will, by statute, cause tree months after the mailing date of	OF THIS COMMUNIC In no event, however, may a re by and will expire SIX (6) MONT the application to become ABA	ATION. ply be timely filed HS from the mailing date of this communication. ANDONED (35 U.S.C. § 133).	
Status				
 Responsive to communicate This action is FINAL. Since this application is in a closed in accordance with the 	2b)⊠ This action for allowance e	on is non-final. xcept for formal matte	rs, prosecution as to the merits is 11, 453 O.G. 213.	
Disposition of Claims				
4) ⊠ Claim(s) 1-18 is/are pendin 4a) Of the above claim(s) 1- 5) □ Claim(s) is/are allow 6) ⊠ Claim(s) 4-9 is/are rejected 7) □ Claim(s) is/are object 8) □ Claim(s) are subject	. <u>3 and 10-18</u> is/are withd ed. .ted to.		on.	
Application Papers				
9) The specification is objected 10) The drawing(s) filed on 18 A Applicant may not request that Replacement drawing sheet(s) The oath or declaration is old	lovember 2003 is/are: a any objection to the drawin including the correction is	ng(s) be held in abeyand required if the drawing(s	ee. See 37 CFR 1.85(a). s) is objected to. See 37 CFR 1.121(d).	
Priority under 35 U.S.C. § 119				
2. Certified copies of the3. Copies of the certified	one of: e priority documents hav e priority documents hav d copies of the priority do nternational Bureau (PC	e been received. e been received in Ap ocuments have been r T Rule 17.2(a)).	plication No eceived in this National Stage	
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing 3) Information Disclosure Statement(s) (PT Paper No(s)/Mail Date 12/19/03.	Review (PTO-948) O-1449 or PTO/SB/08)	Paper No(s)	nmary (PTO-413) /Mail Date ormal Patent Application (PTO-152)	

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Detailed Action

Applicant's election without traverse of Group II (claims 4-9) in the reply filed on 11/21/05 is acknowledged.

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 4-9 are rejected under 35 U.S.C. 103(a) as being unpatentable over Miyamae (6,866,969) in view of Matsushita (JP10-10308).

The claimed invention is directed to a method for producing a hologram element, employing a photomask which comprises a plurality of mask regions for forming the diffraction gratings of the respective regions of the hologram, the mask regions being composed of a non-light-transmitting mask portion and a light-transmitting portion, wherein, of the plurality of mask regions, at least two mask regions are configured differently from each other in arrangement interval at which the light-transmitting portions are arranged in an alignment direction, and in ratio of an alignment-direction-wise width for the light-transmitting portions to the alignment-direction-wise arrangement interval for the light-transmitting portions.

And wherein the ratio of the alignment-direction-wise width to the alignment-direction-wise arrangement interval for the light-transmitting portions in a mask region having a shorter light-transmitting-portion arrangement interval is made smaller than the ratio of the alignment-direction-wise width to the alignment-direction-wise arrangement interval for the light-transmitting portions in a mask region having a longer light-transmitting-portion arrangement interval.

Miyamae teaches a photomask that has a transparent substrate (42), and a phase grating structured from a plurality of grooves of a fixed pitch (P) formed on said substrate, wherein at least either the depth or width of the respective grooves of the phase grating is made to bear the exposure pattern.

Miyamae also teaches a manufacturing method of a phase grating mask, comprising: an exposure step for forming on a resist a latent image of the phase grating mask containing a plurality of grooves in prescribed intervals; a development step for developing said resist and forming a phase grating resist; wherein said exposure step scans said resist and sets the depth of the exposure groove formed on said resist with the exposure beam in which the intensity thereof has been modulated in correspondence with the pattern of said phase grating mask; wherein at least either the depth or width of the respective grooves of said phase grating determines the 0 order optical transmittance of the exposed light that vertically crosses one face of said substrate: wherein the 0 order optical transmittance setting at said grooves forms the exposure pattern.

The teachings of Miyamae differ from those of the applicant in that the applicant teaches adjusting the diffraction efficiency of the first order diffracted light.

JP10-10308 teaches adjusting the diffraction efficiency of the first order diffracted light.

It would have been obvious to one having ordinary skill in the art to take the teachings of Miyamae and combine them with the teachings of JP10-10308 in order to make the claimed invention because the use and advantages of photolithography for adjusting the interval of closely spaced features is well known and it would have been obvious for one to take advantage of this technique.

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Conclusion

Any inquiry concerning this communication or earlier communications from the Examiner should be directed to Stephen Rosasco whose telephone number is (571) 272-1389. The Examiner can normally be reached Monday-Friday, from 8:00 AM to 4:30 PM. The Examiner's supervisor, Mark Huff, can be reached on (571) 272-1385. The fax phone number for the organization where this application or proceeding is assigned is (571) 273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

S. Rosasco

Primary Examiner
Art Unit 1756

S.Rosasco 2/3/06